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Kind regards,

Team Nexperia





100 V, 1 A NPN low V<sub>CEsat</sub> (BISS) transistor Rev. 02 — 11 December 2009

Product data sheet

#### **Product profile** 1.

### 1.1 General description

NPN low V<sub>CEsat</sub> transistor in a plastic SOT457 (SC-74) package.

### 1.2 Features

- SOT457 package
- Low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- High efficiency, leading to less heat generation

### 1.3 Applications

- Major application segments:
  - Automotive 42 V power
  - Telecom infrastructure
  - Industrial
- DC-to-DC converter
- Peripheral driver
  - Driver in low supply voltage applications (e.g. lamps and LEDs)
  - Inductive load drivers (e.g. relays, buzzers and motors)

### 1.4 Quick reference data

Table 1.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage		-	-	100	V
I <sub>C</sub>	collector current (DC)		-	-	1	А
I <sub>CM</sub>	peak collector current		-	-	3	А
R <sub>CEsat</sub>	equivalent on-resistance		-	-	200	mΩ



### 2. Pinning information

Table 2.	Discrete pinning	
Pin	Description	Simplified outline Symbol
1, 2, 5, 6	collector	
3	base	
4	emitter	
		sym014

## 3. Ordering information

Table 3. Ordering information				
Type number	Package			
	Name	Description	Version	
PBSS8110D	-	plastic surface mounted package; 6 leads	SOT457	

### 4. Marking

Table 4. Marking	
Type number	Marking code <sup>[1]</sup>
PBSS8110D	A8

[1] Made in Malaysia

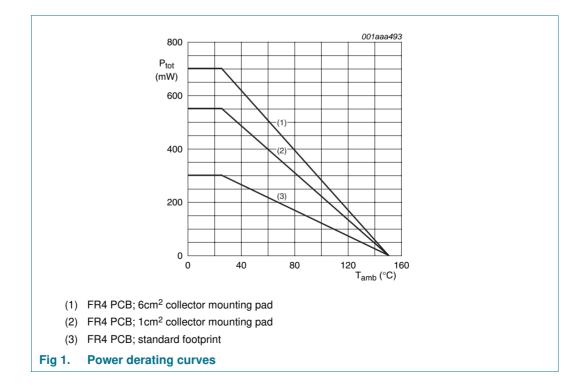
### 5. Limiting values

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	120	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	100	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
I <sub>CM</sub>	peak collector current	T <sub>j(max)</sub>		-	3	А
I <sub>C</sub>	continuous collector current			-	1	А
I <sub>B</sub>	continuous base current			-	0.3	А
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1]	-	300	mW
			[2]	-	550	mW
			[3]	-	700	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	operating ambient temperature			-65	+150	°C
T <sub>stg</sub>	storage temperature			-65	+150	°C

[1] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated, standard footprint.

[2] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated, 1cm<sup>2</sup> collector mounting pad.

[3] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated, 6cm<sup>2</sup> collector mounting pad.



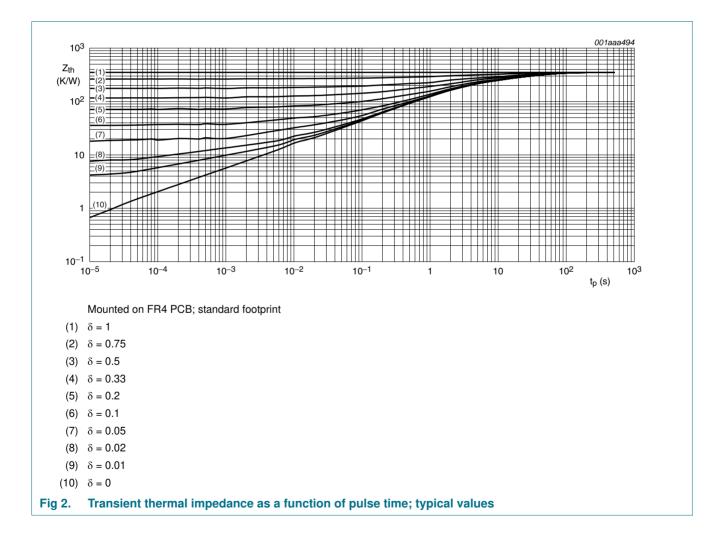
### 6. Thermal characteristics

Table 6.	Thermal characteristics				
Symbol	Parameter	Conditions		Тур	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	416	K/W
			[2]	227	K/W
			[3]	178	K/W
$R_{th(j\text{-}s)}$	thermal resistance from junction to soldering point	in free air	<u>[1]</u>	83	K/W

[1] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated, standard footprint.

[2] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated, 1cm<sup>2</sup> collector mounting pad.

[3] Device mounted on a FR4 printed-circuit board, single-sided copper, tin-plated, 6cm<sup>2</sup> collector mounting pad.



### 7. Characteristics

### Table 7. Characteristics

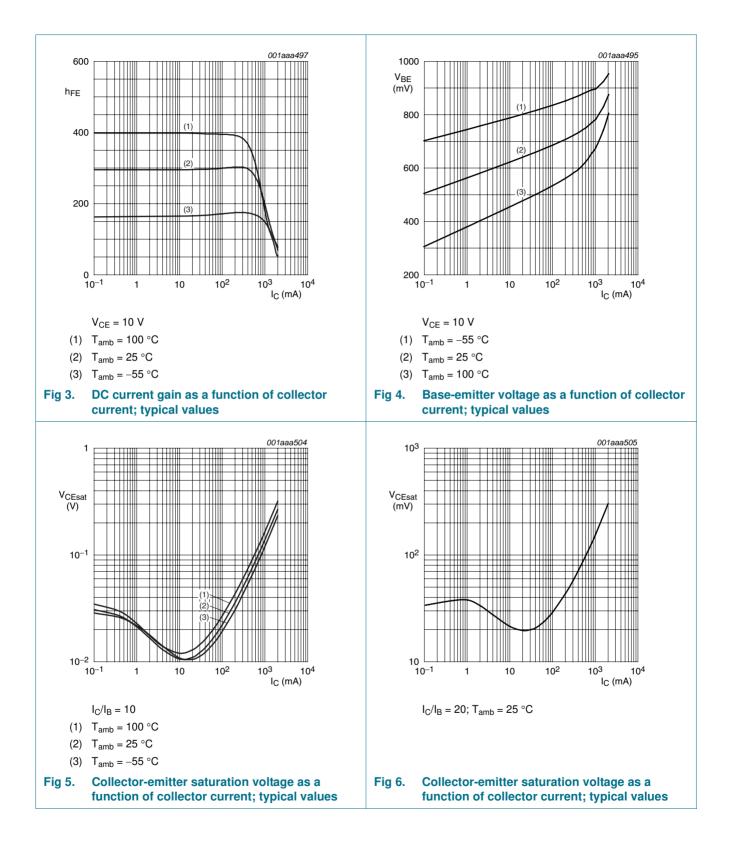
 $T_j = 25 \ ^{\circ}C$  unless otherwise specified.

Parameter	Conditions		Min	Тур	Max	Unit
collector-base cut-off	$V_{CB} = 80 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
current	$\label{eq:VCB} \begin{array}{l} V_{CB} = 80 \ V; \ I_E = 0 \ A; \\ T_j = 150 \ ^{\circ}C \end{array}$		-	-	50	μA
collector-emitter cut-off current	$V_{CE} = 80 \text{ V};  V_{BE} = 0 \text{ V}$		-	-	100	nA
emitter-base cut-off current	$V_{EB} = 4 \text{ V}; I_C = 0 \text{ A}$		-	-	100	nA
DC current gain	$V_{CE} = 10 \text{ V}; I_{C} = 1 \text{ mA}$		150	-	-	
	$V_{CE} = 10 \text{ V}; I_{C} = 250 \text{ mA}$		150	-	500	
	$V_{CE} = 10 \text{ V}; I_{C} = 0.5 \text{ A}$	<u>[1]</u>	100	-	-	
	$V_{CE} = 10 \text{ V}; I_{C} = 1 \text{ A}$	[1]	80	-	-	
collector-emitter saturation voltage	$I_{C} = 100 \text{ mA}; I_{B} = 10 \text{ mA}$		-	-	40	mV
	$I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}$		-	-	120	mV
	$I_{C} = 1 \text{ A}; I_{B} = 100 \text{ mA}$		-	-	200	mV
equivalent on-resistance	I <sub>C</sub> = 1 A; I <sub>B</sub> = 100 mA	[1]	-	160	200	mΩ
base-emitter saturation voltage	I <sub>C</sub> = 1 A; I <sub>B</sub> = 100 mA		-	-	1.05	V
base-emitter turn-on voltage	$V_{CE} = 10 \text{ V}; I_{C} = 1 \text{ A}$		-	-	0.9	V
transition frequency	$V_{CE} = 10 \text{ V}; I_{C} = 50 \text{ mA};$ f = 100 MHz		100	-	-	MHz
collector capacitance	$V_{CB} = 10 \text{ V}; \text{ I}_E = \text{ I}_e = 0 \text{ A};$ f = 1 MHz		-	-	7.5	pF
	collector-base cut-off currentcollector-emitter cut-off currentemitter-base cut-off currentDC current gainDC current gaincollector-emitter saturation voltageequivalent on-resistancebase-emitter saturation voltagebase-emitter turn-on voltagetransition frequency					

[1] Pulse test  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

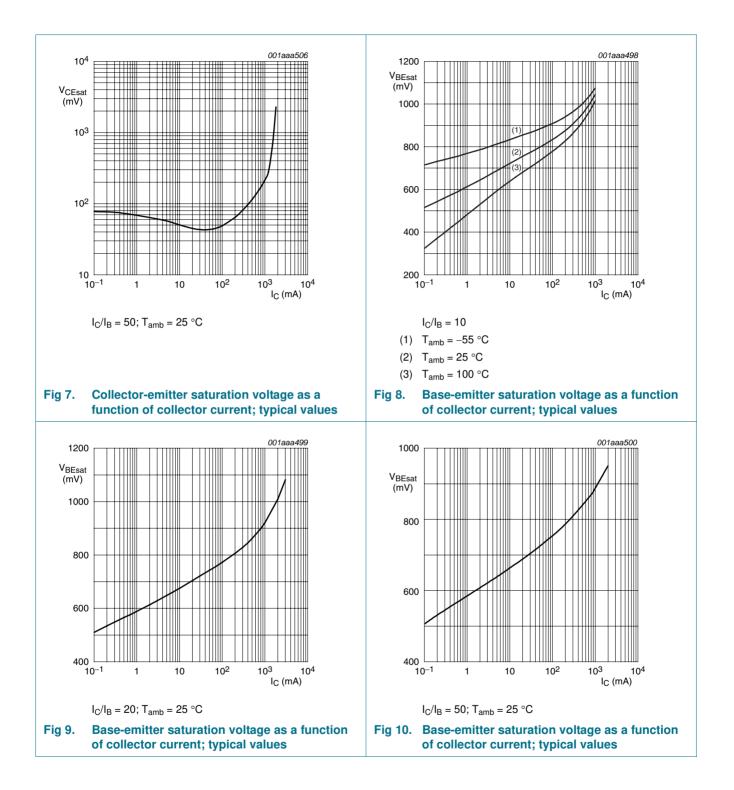
# **PBSS8110D**

### 100 V, 1 A NPN low V<sub>CEsat</sub> (BISS) transistor



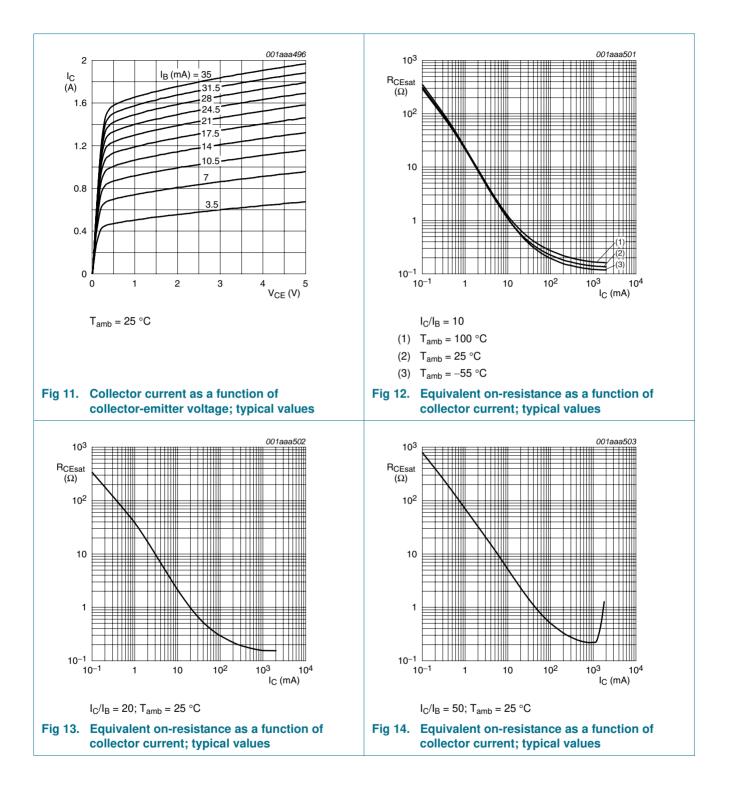
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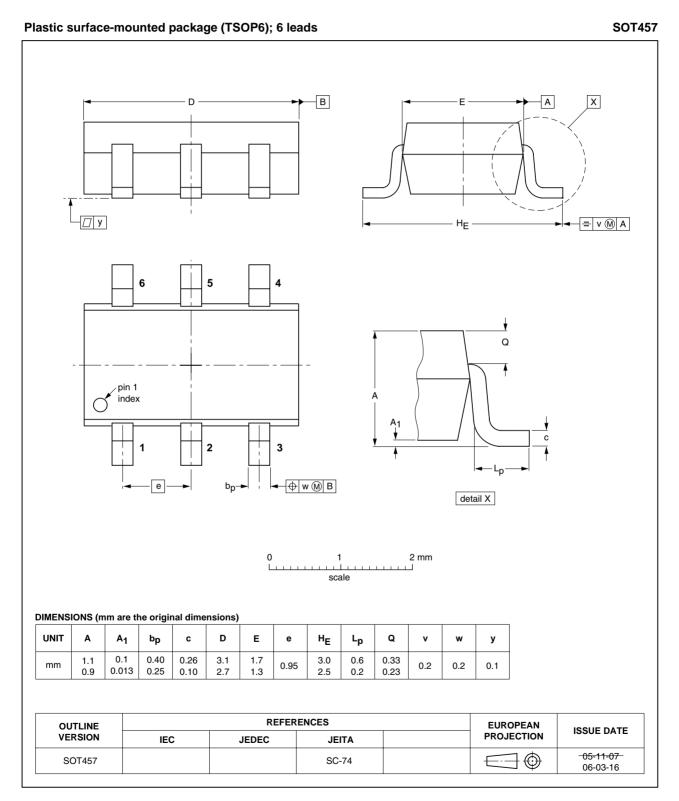


# PBSS8110D

### 100 V, 1 A NPN low V<sub>CEsat</sub> (BISS) transistor



### 8. Package outline



#### Fig 15. Package outline

### 9. Revision history

Table 8.   Revision	history					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
PBSS8110D_2	20091211	Product data	-	PBSS8110D_1		
Modifications:	including new content. • <u>Table 2 "Disc</u>	eet was changed to reflect w legal definitions and disc crete pinning": amended	laimers. No changes w	ere made to the technical		
	<ul> <li>Figure 3 "DC current gain as a function of collector current; typical values": updated</li> <li>Figure 11: updated</li> </ul>					
	• Figure 15 "P	ackage outline": updated				
PBSS8110D_1	20040423	Product data	-	-		

### **10. Legal information**

### 10.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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